



100V N-Channel Enhancement Mode MOSFET

Voltage 100 V Current 5 A

Features

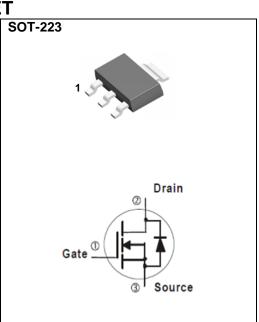
- R_{DS(ON)}, V_{GS}@10V, I_D@2.5A<130mΩ
- $R_{DS(ON)}$, $V_{GS}@6V$, $I_{D}@1A<135m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-223 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.043 ounces, 0.123 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|------------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | 100 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current (Note 4) | T _C =25°C | l _D - | 5 | А | |
| | T _C =100°C | | 3.1 | | |
| Pulsed Drain Current (Note 1) | T _C =25°C | I _{DM} | 10 | | |
| Power Dissipation | T _C =25°C | Po | 8 | 147 | |
| | T _C =100°C | | 3.2 | W | |
| Continuous Drain Current (Note 4) | T _A =25°C | | 3.1 | А | |
| | T _A =70°C | l _D | 2.5 | | |
| Power Dissipation | T _A =25°C | Po | 3.1 | 14/ | |
| | T _A =70°C | | 2 | W | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | °C | |
| Typical Thermal Resistance (Note 4,5) | Junction to Case | $R_{	heta JC}$ | 15.6 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 40.3 | | |

• Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|--|------|------|--------------|-------|
| Static | | | • | • | | • |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 100 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 2 | 2.76 | 3.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =2.5A | - | 110 | 130 | mΩ |
| | | V_{GS} =6V, I_D =1A | - | 120 | 135 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =100V, V _{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V, V _{DS} =0V | - | - | <u>+</u> 100 | nA |
| Dynamic (Note 6) | | | | | | |
| Total Gate Charge | Qg | V _{DS} =37.5V, I _D =5A, V _{GS} =10V ^(Note 2,3) | - | 12 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 3.1 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 2.2 | - | |
| Input Capacitance | Ciss | V _{DS} =30V, V _{GS} =0V, | - | 707 | - | pF |
| Output Capacitance | Coss | | - | 40 | - | |
| Reverse Transfer Capacitance | Crss | f=1MHZ | - | 16 | - | |
| Turn-On Delay Time | td _(on) | V_{DS} =37.5V, R _L =7.5 Ω , V_{GS} =10V, R _G =3 Ω (Note 2,3) | - | 6 | - | ns |
| Turn-On Rise Time | t _r | | - | 27 | - | |
| Turn-Off Delay Time | td _(off) | | - | 15 | - | |
| Turn-Off Fall Time | t _f | | - | 7 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source | | | | | 5 | Α |
| Diode Forward Current | I _S | | _ | - | ິວ | A |
| Diode Forward Voltage | V_{SD} | I _S =1A, V _{GS} =0V | - | 0.78 | 1 | V |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

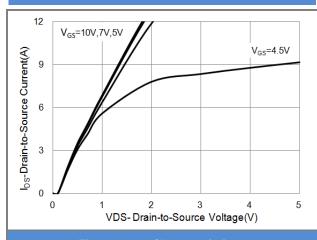


Fig.1 Output Characteristics

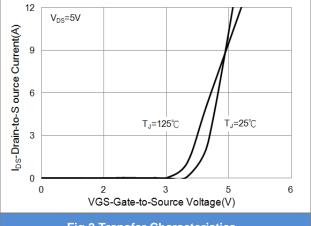


Fig.2 Transfer Characteristics

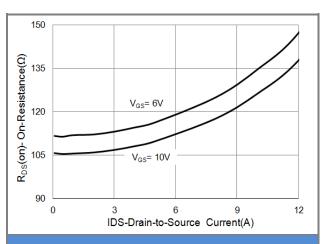


Fig.3 On-Resistance vs. Drain Current

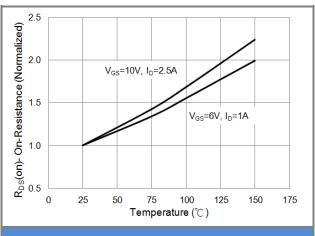
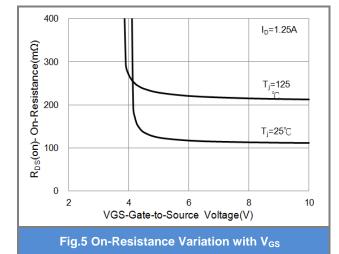


Fig.4 On-Resistance vs. Junction temperature



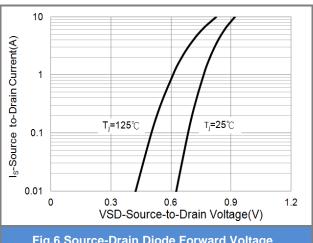


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

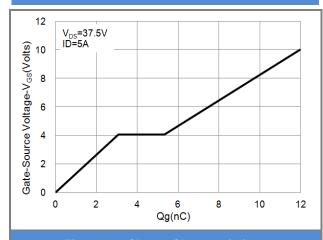


Fig.7 Gate-Charge Characteristics

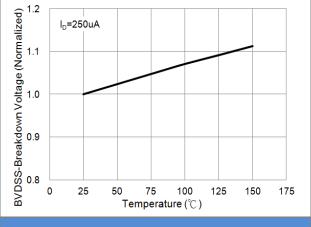


Fig.8 Breakdown Voltage Variation vs. Temperature

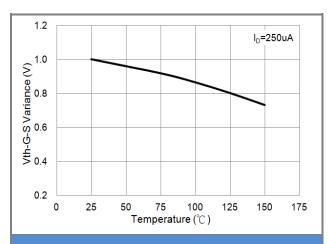


Fig.9 Threshold Voltage Variation with Temperature

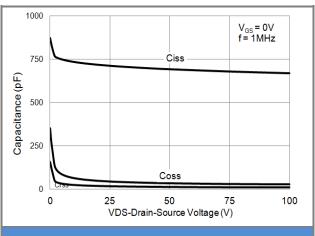


Fig.10 Capacitance vs. Drain-Source Voltage

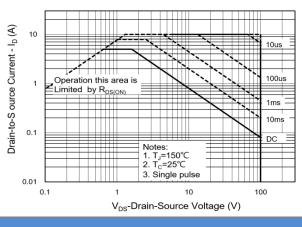


Fig.11 Maximum Safe Operating Area

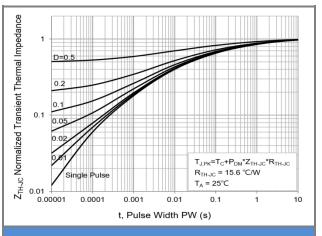


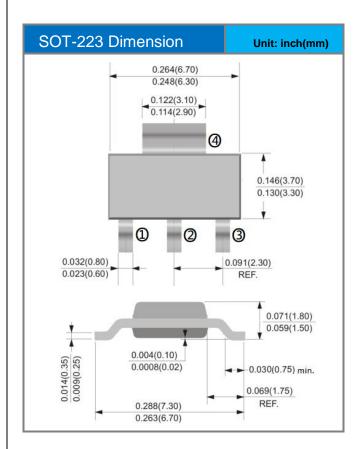
Fig.12 Normalized Transient Thermal Impedance

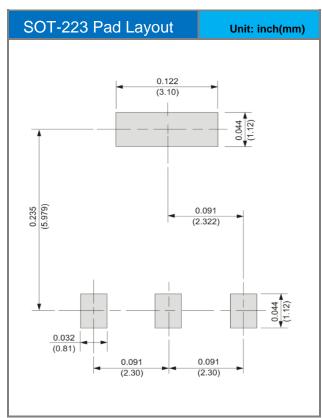
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Packaging Information & Mounting Pad Layout









Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|----------------------|--------------|---------------------|---------|--------------|--|
| PJW5N10-AU_R2_000A1 | SOT-223 | 2,500pcs / 13" reel | W5N10 | Halogen free | |

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